

August 2009

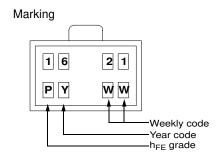
KSD1621 **NPN Epitaxial Silicon Transistor**

Features

- · High Current Driver Applications
- · Low Collector-Emitter Saturation Voltage
- · Large Current Capacity and Wide SOA
- · Fast Switching Speed
- · Complement to KSB1121



1. Base 2. Collector 3. Emitter



Absolute Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	2	Α
P _C	Collector Power Dissipation (T _A = 25°C) Derating Rate above 25°C	500 4	mW mW/°C
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Mounted on Ceramic Board (250mm² x 0.8mm)

Electrical Characteristics $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_E = 0$	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 1 \text{mA}, I_B = 0$	25			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	6			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 20V, I_{E} = 0$			100	nA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 4V, I_{C} = 0$			100	nA
h _{FE1} h _{FE2}	DC Current Gain	$V_{CE} = 2V, I_{C} = 0.1A$ $V_{CE} = 2V, I_{C} = 1.5A$	100 65		560	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 1.5A, I_B = 75mA$		0.18	0.4	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 1.5A, I_B = 75mA$		0.85	1.2	V
f _T	Current Gain Bandwidth product	$V_{CE} = 10V, I_{C} = 50mA$		150		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		19		pF
t _{ON}	Turn On Time *	V _{CC} = 12V, V _{BE} = 5V		60		ns
t _{STG}	Storage Time *	$I_{B1} = -I_{B2} = 25mA$	•	500		ns
t _F	Fall Time *	$I_C = 0.5A, R_L = 25\Omega$		25		ns

hFE Classification

Classification	R	S	Т	U
h _{FE}	100 ~ 200	140 ~ 280	200 ~ 400	280 ~ 560

Package Marking and Ordering Information

Device	Device Marking	Package	Reel Size	Tape Width	Quantity
KSD1621RTF	Line 1: 1621 Line 2: R&3	SOT-89	13"		4,000
KSD1621STF	Line 1: 1621 Line 2: S&3	SOT-89	13"		4,000
KSD1621TTF	Line 1: 1621 Line 2: T&3	SOT-89	13"		4,000
KSD1621UTF	Line 1: 1621 Line 2: U&3	SOT-89	13"		4,000

Typical Performance Characteristics

Figure 1. Static Characteristic

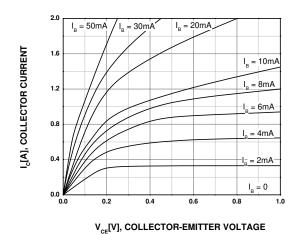
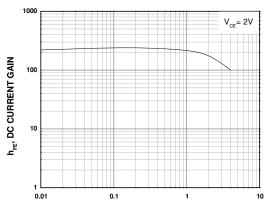


Figure 2. DC Current Gain



 $I_{c}[A]$, COLLECTOR CURRENT

Figure 3. Collector-Emitter Saturation Voltage

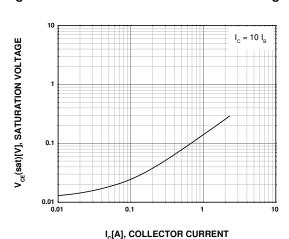
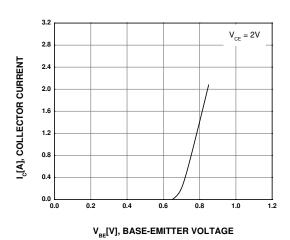


Figure 4. Base-Emitter On Voltage



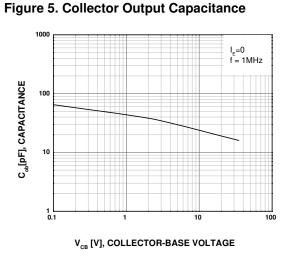
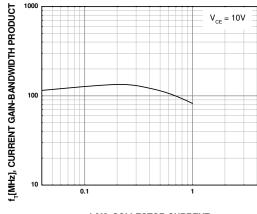


Figure 6. Current Gain Bandwidth Product



I_[A], COLLECTOR CURRENT

Typical Performance Characteristics (Continued)

Figure 7. Safe Operating Area

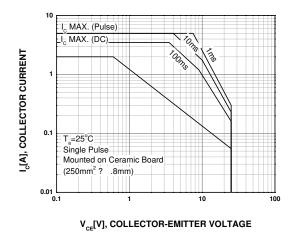
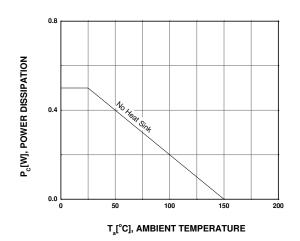
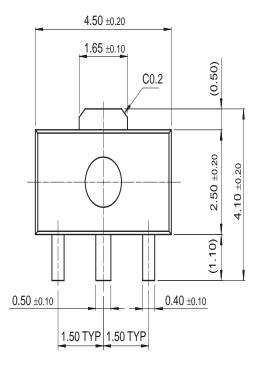


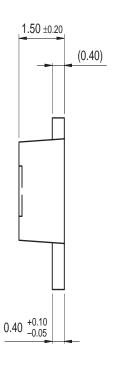
Figure 8. Power Derating

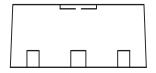


Mechanical Dimensions

SOT-89







Dimensions in Millimeters





The Power Franchise®

⊍wer

franchise

TinyBoost™

TinyBuck™

TinyCalc™

TinyLogic[®]

TINYOPTO™

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